





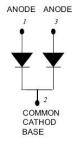
300CNQ035/300CNQ040/300CNQ045 SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for
- enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- · High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage	V_{RRM}	-	35	300CNQ035	
Working Peak Reverse Voltage	V_{RWM}		40 300CNQ040		V
DC Blocking Voltage	VR		45	300CNQ045	
Average Rectified Forward Current	1	50% duty cycle @T _C =104°C,	150(Per Leg)		А
Average Nectified Forward Current	$I_{F(AV)}$	rectangular wave form	300(Per Device)		
Peak One Cycle Non-Repetitive				2880	Α
Surge Current (Per Leg)	I _{FSM}	8.3 ms, half Sine pulse	2000		A
Non-Repetitive Avalanche Energy(Peg Leg)	E _{AS}	T _J =25℃,I _{AS} =30A,L=0.67mH	150		mJ
Repetitive Avalanche Current		Current decaying linearly to zero			
(Peg Leg)	I _{AR}	in 1 µsec Frequency limited by		30	Α
		T _J max. V _A =1.5×V _R typical			

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 150A, Pulse, T _J = 25 °C @ 300A, Pulse, T _J = 25 °C	0.55 0.69	0.61 0.77	V
	V _{F2}	@ 150A, Pulse, T _J = 125 °C @ 300A, Pulse, T _J = 125 °C	0.52 0.64	0.62 0.75	٧
Reverse Current(Per Leg)*	I _{R1}	$@V_R = \text{rated } V_{R,} T_J = 25 ^{\circ}\text{C}$	0.5	15	mA
	I _{R2}	$@V_R = \text{rated } V_{R,} T_J = 125 ^{\circ}\text{C}$	99	750	mA
Junction Capacitance(Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	6500	7750	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

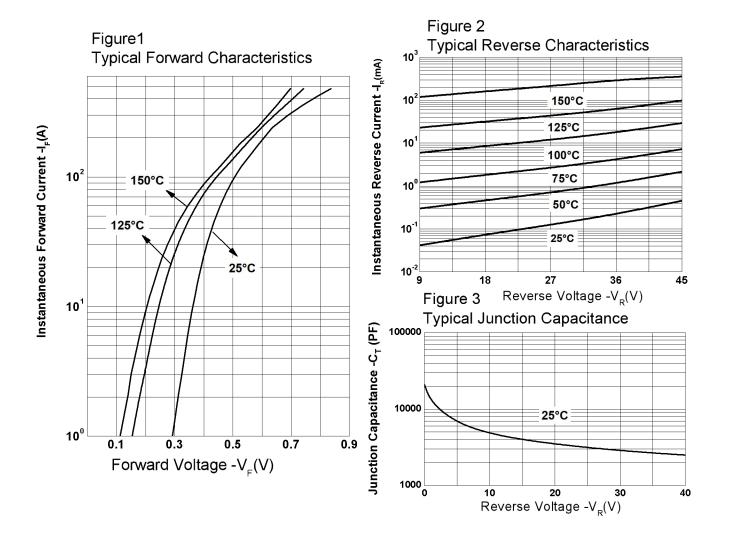
Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +150		°C
Storage Temperature	T _{stg}	-	-55 to +150		°C
Typical Thermal Resistance Junction to Case(Per leg)	$R_{ heta JC}$	DC operation	0.40		°C/W
Typical Thermal Resistance Junction to Case(Per package)	$R_{ heta JC}$	DC operation	0.20		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.08		°C/W
Mounting Torque	т		Mounting Torque	24(min) 35(max)	Kg-cm
Mounting Torque	T _M	-	Terminal Torque	35(min) 46(max)	Ng-cill
Approximate Weight	wt	-	91		g
Case Style	PRM4 Non-Isolated				







Ratings and Characteristics Curves

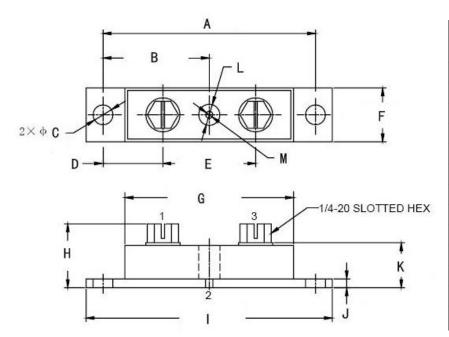






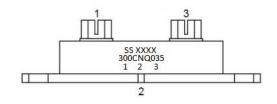


Mechanical Dimensions PRM4 Non-Isolated (Millimeters/Inches)



SYMBOL	Millimeters		Inches	
STIVIBUL	Min.	Max.	Min.	Max.
Α	78.74	81.28	3.100	3.200
В	37.47	42.55	1.475	1.675
С	6.89	7.69	0.271	0.303
D	19.51	24.59	0.768	0.968
E	33.02	38.10	1.300	1.500
F	17.78	20.32	0.700	0.800
G	60.96	64.77	2.400	2.550
Н	17.26	23.25	0.680	0.915
I	90.17	92.71	3.550	3.650
J	3.02	3.68	0.119	0.145
K	14.30	16.15	0.563	0.636
L	9.27	10.79	0.365	0.425
М	4.37	5.28	0.172	0.208

Marking Diagram



Where XXXX is YYWW

300CNQ035 = Part name SS = SS YY = Year WW = Week

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping	
300CNQ SERIES	PRM4(Non- Isolated) (Pb-Free)	9 pcs/box	

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